

MPS651

Switching and Amplifier Applications



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	80	V
V_{CEO}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	0.8	Α
P _C	Collector Dissipation	625	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

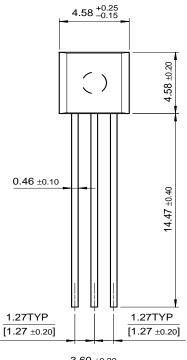
$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

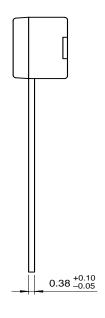
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Voltage	I _C =100μA, I _E =0	80			V
BV _{CEO}	Collector-Emitter Voltage	I _C =10mA, I _B =0	60			V
BV _{EBO}	Emitter- Base Voltage	$I_{C}=10\mu A, I_{C}=0$	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =80V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} =4.0V, I _C =0			0.1	μΑ
h _{FE1} h _{FE2} h _{FE3} h _{FE4}	DC Current Gain	$\begin{array}{c} V_{\text{CE}} = 2\text{V, I}_{\text{C}} = 50\text{mA} \\ V_{\text{CE}} = 2\text{V, I}_{\text{C}} = 500\text{mA} \\ V_{\text{CE}} = 2\text{V, I}_{\text{C}} = 1.0\text{A} \\ V_{\text{CE}} = 2\text{V, I}_{\text{C}} = 2.0\text{A} \end{array}$	75 75 75 40			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =1.0A, I _B =100mA I _C =2.0A, I _B =200mA			300 500	mV
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =1.0A, I _B =100mA			1.2	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =2.0V, I _C =1.0A			1.0	V
f _T	Current Gain Band Width Product	V _{CE} =5.0V, I _C =50mA, f=100MHz	75			MHz

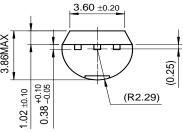
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Package Dimensions

TO-92







Dimensions in Millimeters

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